Unit: mm

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

2SC4682

Strobe Flash Applications Medium Power Amplifier Applications

• Excellent hfe linearity: hfe (1) = 800 to 3200 (VCE = 1 V, IC = 0.5 A)

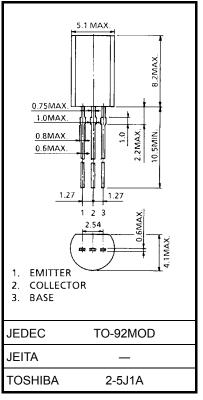
 $h_{FE}(2) = 500 \text{ (typ.) (VCE} = 1 \text{ V, IC} = 3 \text{ A)}$

• Low saturation voltage: V_{CE} (sat) = 0.5 V (max)

(IC = 3 A, IB = 30 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	30	V	
Collector-emitter voltage		V _{CES}	30	V	
		V (BR) CEO	15		
Emitter-base voltage		V _{EBO}	6	V	
Collector current	DC	IC	3	А	
	Pulse	I _{CP}	6		
Base current		Ι _Β	0.8	Α	
Collector power dissipation		PC	900	mW	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 0.36 g (typ.)

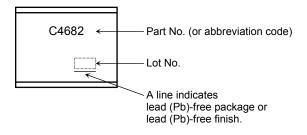
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

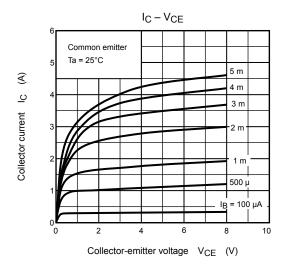
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

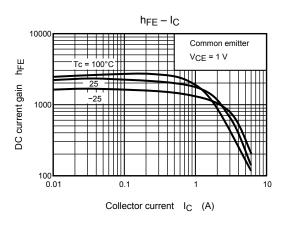
Electrical Characteristics (Ta = 25°C)

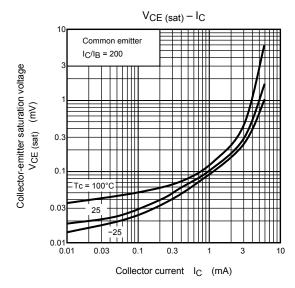
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 30 V, I _E = 0	_	_	1	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} = 6 V, I _C = 0	_	_	10	μA
Collector-emitter breakdown voltage	V (BR) CEO	I _C = 10 mA, I _B = 0	15	_	_	٧
DC current gain	h _{FE (1)}	V _{CE} = 1 V, I _C = 0.5 A	800	_	3200	
	h _{FE (2)}	V _{CE} = 1 V, I _C = 3 A	300	500	_	
Collector-emitter saturation voltage	V _{CE} (sat)	I _C = 3 A, I _B = 30 mA	_	0.25	0.5	٧
Base-emitter voltage	V _{BE}	V _{CE} = 1 V, I _C = 3 A	_	0.85	1.2	V
Transition frequency	f _T	V _{CE} = 1 V, I _C = 0.5 A	_	150	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	30	_	pF

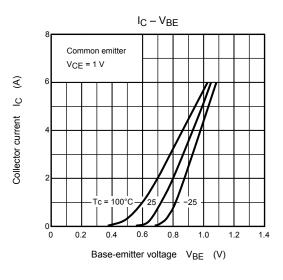
Marking

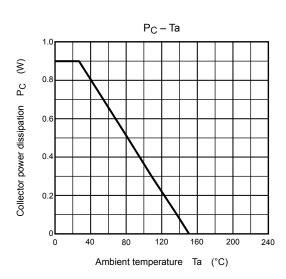


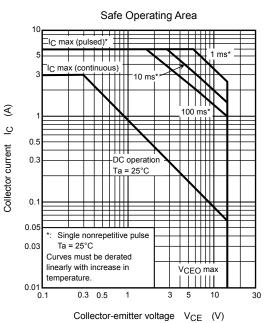












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